

DESCRIPTION

The SN75LBC184 and SN65LBC184 are differential data line transceivers in the trade-standard footprint of the SNx5LBC184 with built-in protection against high-energy noise transients. This feature provides a substantial increase in reliability for better immunity to noise transients coupled to the data cable over most existing devices. Use of these circuits provides a reliable low-cost direct-coupled (with no isolation transformer) data line interface without requiring any external components.

The SN75LBC184 and SN65LBC184 can withstand overvoltage transients of 400-W peak (typical). The conventional combination wave called out in IEC 61000-4-5 simulates the overvoltage transient and models a unidirectional surge caused by overvoltages from switching and secondary lightning transients.

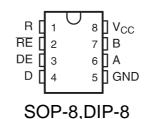
APPLICATIONS

- Industrial Networks
- Utility Meters
- Motor Control

FEATURES

- Integrated Transient Voltage Suppression
- ESD Protection for Bus Terminals Exceeds: ±30 kV IEC 61000-4-2, Contact Discharge ±15 kV IEC 61000-4-2, Air-Gap Discharge ±15 kV EIA/JEDEC Human Body Model
- Circuit Damage Protection of 400-W Peak
 (Typical) Per IEC 61000-4-5
- Controlled Driver Output-Voltage SlewRates
 Allow Longer Cable Stub Lengths
- 250-kbps in Electrically NoisyEnvironments
- · Open-Circuit Fail-Safe Receiver Design
- 1/4 Unit Load Allows for 128 Devices ConnectedonBus
- Thermal Shutdown Protection
- Power-Up/-Down Glitch Protection
- Each Transceiver Meets or Exceeds the Requirements of TIA/EIA-485 (RS-485) and ISO/IEC 8482:1993(E) Standards
- Low Disabled Supply Current 300 µA Max
- Pin Compatible With SNx5LBC184

PIN CONFIGURATION



Pin Functions

Р	IN	1/0	DECODIDATION	
NAME	NO.	- I/O	DESCRIPTION	
А	6	Bus input/output	Driver output or receiver input (complementary to B)	
В	7	Bus input/output	Driver output or receiver input (complementary to A)	
D	4	Digital input	Driver data input	
DE	3	Digital input	Active-HIGH driver enable	
GND	5	Reference potential	Local device ground	
R	1	Digital output	Receiver data output	
RE	2	Digital input	Active-LOW receiver enable	
V _{CC}	8	Supply	4.75-V to 5.25-V supply	



BLOCK DIAGRAM

LOGIC SYMBOL

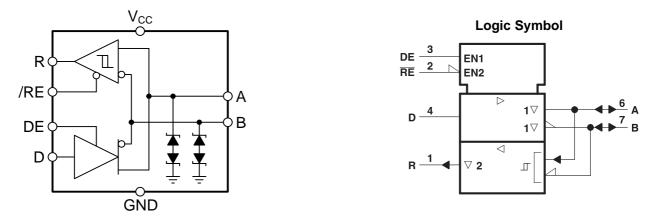


Figure 13. Functional Logic Diagram

OVERVIEW

The SNx5LBC184 device is a 5-V, half-duplex, RS-485 transceiver with integrated transient voltage suppressors that prevent circuit damage in the presence of high-energy transients of up to 400-W peak power. This transceiver has an active-HIGH driver enable and active-LOW receiver enable. The differential driver is suitable for data transmission up to 250 kbps.

FEATUER DESCRIPTION

Integrated transient voltage suppressors protect the transceiver against Electrostatic Discharges (ESD) according to IEC 61000-4-2 of up to \pm 30 kV and surge transients according to IEC 61000-4-5 of up to 400-W peak.

The differential driver incorporates slew-rate controlled outputs sufficient to transmit data up to 250 kbps. Slewrate control allows for longer unterminated cable runs and longer stub lengths from the main cable trunk than with faster voltage transitions. A unique receiver design provides a high level failsafe output when the inputs are left floating.

left floating. The SN65LBC184 is characterized from –40°C to 85°C and the SN75LBC184 is characterized from 0°C to 70°C.

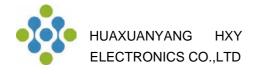
INPUT	ENABLE	OUTPUTS				
D DE		Α	В			
Н	Н	Н	L			
L	Н	L	Н			
Х	L	Z	Z			

DRIVER	FUNCTION TABLE	Ξ
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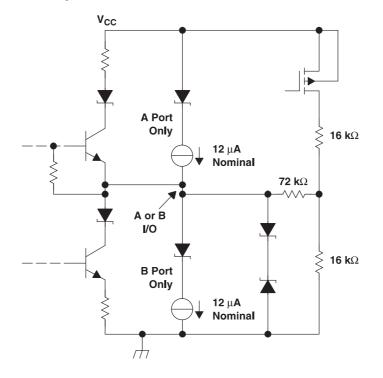
H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)

REGENTERTOR		-
DIFFERENTIAL INPUTS	ENABLE	OUTPUT
A – B	RE	R
$V_{ID} \ge 0.2 V$	L	Н
$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$	L	?
$V_{ID} \leq -0.2 V$	L	L
Х	Н	Z
Open	L	Н

RECEIVER FUNCTION TABLE



Schematic of Inputs and Outputs



SPECIFICATIONS

Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

SYMBOL	PARAMETER	MIN	MAX	UNIT
	Supply voltage ⁽²⁾	-0.5	7	V
V _{CC}	Continuous voltage range at any bus terminal	-15	15	V
	Data input/output voltage	-0.3	7	V
I _O	Receiver output current	-20	20	mA
	Continuous total power dissipation ⁽³⁾	Internally	y Limited	
T _{stg}	Storage temperature		160	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential input/output bus voltage, are with respect to network ground terminal.

(3) The driver shuts down at a junction temperature of approximately 160°C. To operate below this temperature, see the Dissipation Ratings.

ESD Ratings

SYMBO	OL	PARAMETER		VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC	A, B, GND	±15000	
		JS-001 ⁽¹⁾	All pins IEC61000-4-2) A, B, GND ⁽²⁾	±3000	
	Electrostatic Contact	Contact discharge (IEC61000-4-2)	A, B, GND ⁽²⁾	±30000	
V _(ESD)	discharge	Air discharge (IEC61000-4-2)	A, B, GND ⁽³⁾	±15000	V
		All pins (Class 3A)		±8000	
		All pins (Class 3B)		±200	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) GND and bus pin ESD protection is beyond readily available test equipment capabilities for IEC 61000-4-2, EIA/JEDEC test method A114-A and MIL-STD-883C method 3015. Ratings listed are limits of test equipment; device performance exceeds these limits.



Recommended Operating Conditions over operating free-air temperature range

SYMBOL	PARAMETER		MIN	TYP	MAX	UNIT
V _{CC}	Supply voltage		4.75	5	5.25	V
V_{I} or V_{IC}	Voltage at any bus terminal (separ	Voltage at any bus terminal (separately or common mode)			12	V
VIH	High-level input voltage	D, DE, and RE	2			V
V _{IL}	Low-level input voltage	D, DE, and RE			0.8	V
V _{ID}	Differential input voltage				12	V
		Driver	-60			
	High-level output current	Receiver	-8			mA
		Driver			60	mA
I _{OL}	Low-level output current	Receiver			4	
-		SN75LBC184	0		70	°C
T _A	Operating free-air temperature	SN65LBC184	-40		85	°C

Thermal Information

	THERMAL METRIC		SNx5LBC184		
SYMBOL			D [SOP-8]	UNIT	
		8 P	INS		
R _{θJA}	Junction-to-ambient thermal resistance	108.7	172.4	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	34.8	42.5	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	23.6	41.4	°C/W	
Ψ _{JT}	Junction-to-top characterization parameter	12	4.6	°C/W	
Ψ_{JB}	Junction-to-board characterization parameter	23.5	40.7	°C/W	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W	

Driver Switching Characteristics over recommended operating conditions (unless otherwise noted)

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{d(DH)}	Differential output delay time, low-to-high-level output				1.3	μs
t _{d(DL)}	Differential output delay time, high-to-low-level output				1.3	μs
t _{PLH}	Propagation delay time, low-to-high-level output			0.5	1.3	μs
t _{PHL}	Propagation delay time, high-to-low-level output	$R_L = 54 \Omega$ $C_L = 50 \text{ pF}$ See Figure 9		0.5	1.3	μs
t _{sk(p)}	Pulse skew ($t_{d(DH)} - t_{d(DL)}$)	0L = 00 p.		75	150	ns
t _r	Rise time, single-ended		0.25		1.2	μs
t _f	Fall time, single-ended	it	0.25		1.2	μs
t _{PZH}	Output enable time to high level	$R_L = 110 \Omega$ See Figure 6			3.5	μs
t _{PZL}	Output enable time to low level	$R_L = 110 \Omega$ See Figure 7			3.5	μs
t _{PHZ}	Output disable time from high level	$R_L = 110 \Omega$ See Figure 6			2	μs
t _{PLZ}	Output disable time from low level	$R_L = 110 \Omega$ See Figure 7			2	μs

Dissipation Ratings

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW
Р	1150 mW	9.2 mW/°C	736 mW	598 mW



Electrical Characteristics: Driver

over recommended operating conditions (unless otherwise noted)

SYMBOL	PARAMETER	ALTERNATE SYMBOLS TEST CONDITIONS		MIN	TYP ⁽¹⁾	МАХ	UNIT
			$DE = \overline{RE} = 5 V$ No Load		12	25	mA
I _{CC}	Supply current	NA	$\frac{DE}{RE} = 0 V$ RE = 5 V No Load		175	300	μA
Iн	High-lev <u>el</u> input current (D, DE, RE)	NA	V ₁ = 2.4 V			50	μA
IIL	Low-level input current (D, DE, RE)	NA	V ₁ = 0.4 V	-50			μA
			$V_{O} = -7 V$	-250	-120		
l _{os}	Short-circuit output current OS ⁽²⁾	NA	$V_{O} = V_{CC}$			250	mA
	current 00		V _O = 12 V			250	
l _{oz}	High-impedance output current	NA	See Receiver II				mA
Vo	Output voltage	V_{oa}, V_{ob}	I _O = 0	0		V _{CC}	V
V _{OC(PP)}	Peak-to-peak change in common-mode output voltage during state transitions	NA	See Figure 9 and Figure 10		0.8		V
V _{oc}	Common-mode output voltage	V _{os}	See Figure 8	1		3	V
∆V _{OC(SS)}	Magnitude of change, common-mode steady- state output voltage	$ V_{os} - V_{os} $	See Figure 10			0.1	V
	Magnitude of		$I_{O} = 0$	1.5		6	V
V _{OD}	differential output voltage $ V_A - V_B $	Vo	$R_L = 54 \Omega$, See Figure 8	1.5			V
Δ V _{OD}	Change in differential voltage magnitude between logic states	$ V_t - V_t $	R _L = 54 Ω			0.1	V

(1) (2)

All typical values are measured with $T_A = 25^{\circ}C$ and $V_{CC} = 5$ V. This parameter is measured with only one output being driven at a time.

Electrical Characteristics: Receiver

over recommended operation conditions (unless otherwise noted)

SYMBOL	PARAMETER	TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
	Supply surrent (total paskage)	$DE = \overline{RE} = 0 V, No$	o Load			3.9	mA
ICC	Supply current (total package)	$\overline{\text{RE}} = 5 \text{ V}, \text{DE} = 0$	V, No Load			300	μA
			V _I = 12 V			250	
lı	land the summer of		$V_{I} = 12 V, V_{CC} = 0$			250	
	Input current	Other input = 0 V	$V_{1} = -7 V$	-200			μA
			$V_{I} = -7 V, V_{CC} = 0$	-200			
I _{OZ}	High-impedance-state output current	$V_0 = 0.4 V$ to 2.4 V				±100	μA
V _{hys}	Input hysteresis voltage				70		mV
V _{IT+}	Positive-going input threshold voltage					200	V
V _{IT-}	Negative-going input threshold voltage			-200			mV
V _{OH}	High-level output voltage	I _{OH} = -8 mA, See Figure 11		2.8			V
V _{OL}	Low-level output voltage	I _{OL} = 4 mA, See F	igure 11			0.4	V

(1) All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



Receiver Switching Characteristics

over recommended operating conditions (unless otherwise noted)

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output				150	ns
t _{PHL}	Propagation delay time, high-to-low-level output	- C _L = 50 pF, See Figure 11			150	ns
t _{sk(p)}	Pulse skew (t _{PHL} - t _{PLH})				50	ns
t _r	Rise time, single-ended	Cas Figure 44		20		ns
t _f	Fall time, single-ended	- See Figure 11		20		ns
t _{PZH}	Output enable time to high level				100	ns
t _{PZL}	Output enable time to low level	See Figure 12			100	ns
t _{PHZ}	Output disable time from high level				100	ns
t _{PLZ}	Output disable time from low level				100	ns

TYPICAL CHARATERISTICS

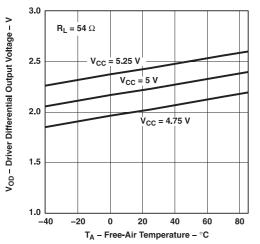


Figure 1. Driver Differential Output Voltage vs Free-Air Temperature

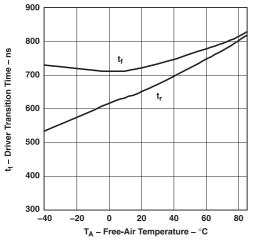


Figure 3. Driver Transition Time vs Free-Air Temperature

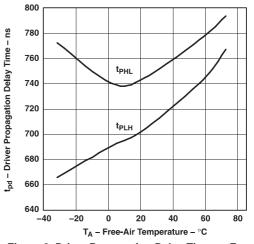


Figure 2. Driver Propagation Delay Time vs Free-Air Temperature

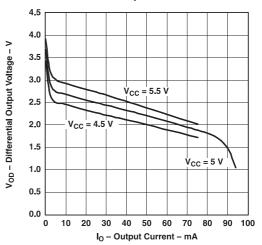


Figure 4. Differential Output Voltage vs Output Current



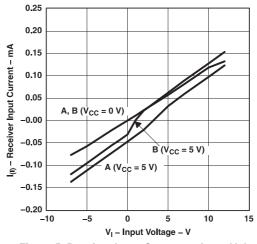
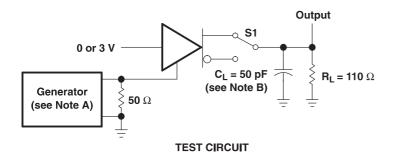
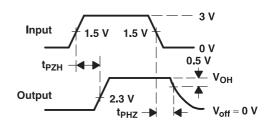


Figure 5. Receiver Input Current vs Input Voltage

PARAMETER MEASUREMENT INFORMATION

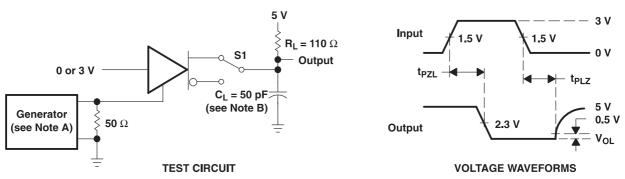




VOLTAGE WAVEFORMS

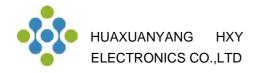
- A. The input pulse is supplied by a generator having the following characteristics: PRR = 1.25 kHz, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns, $Z_O = 50 \Omega$.
- B. C_L includes probe and jig capacitance.

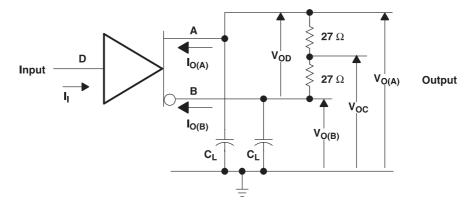
Figure 6. Driver t_{PZH} and t_{PHZ} Test Circuit and Voltage Waveforms



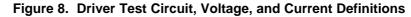
- A. The input pulse is supplied by a generator having the following characteristics: PRR = 1.25 kHz, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns, $Z_0 = 50 \Omega$.
- B. C_L includes probe and jig capacitance.

Figure 7. Driver t_{PZL} and t_{PLZ} Test Circuit and Voltage Waveforms





- A. Resistance values are in ohms and are 1% tolerance.
- B. C_L includes probe and jig capacitance.



PARAMETER MEASUREMENT INFORMATION(CONTINUED)

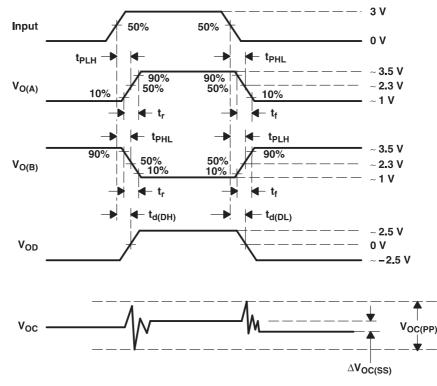
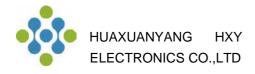
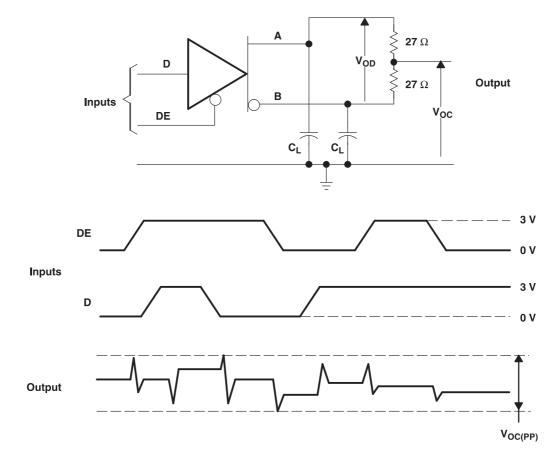


Figure 9. Driver Timing, Voltage, and Current Waveforms

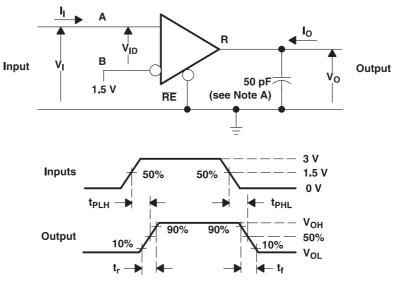


PARAMETER MEASUREMENT INFORMATION(CONTINUED)



- A. Resistance values are in ohms and are 1% tolerance.
- B. C_L includes probe and jig capacitance (±10%).

Figure 10. Driver V_{OC(PP)} Test Circuit and Waveforms

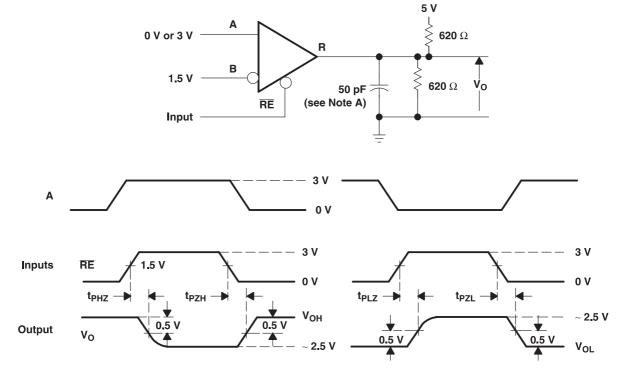


A. This value includes probe and jig capacitance (±10%).

Figure 11. Receiver t_{PLH} and t_{PHL} Test Circuit and Voltage Waveforms



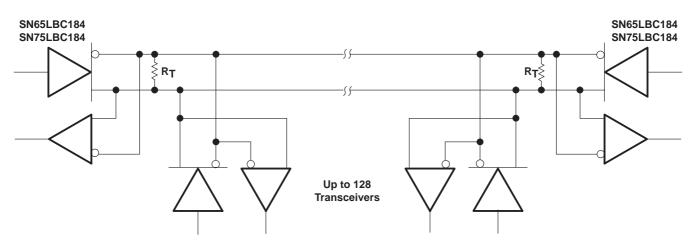
PARAMETER MEASUREMENT INFORMATION(CONTINUED)



A. This value includes probe and jig capacitance (±10%).

Figure 12. Receiver t_{PZL}, t_{PLZ}, t_{PZH}, and t_{PHZ} Test Circuit and Voltage Waveforms

APPLICATION INFORMATION



NOTE A: The line should be terminated at both ends in its characteristic impedance (R_T = Z_O). Stub lengths off the main line should be kept as short as possible.

Figure 13. Typical Application Circuit



SN65LBC184 TEST DESCRIPTION

The SN65LBC184 is tested against the IEC 61000–4–5 recommended transient identified as the combination wave. The combination wave provides a 1.2-/50- μ s open-circuit voltage waveform and a 8-/20- μ s short-circuit current waveform shown in Figure 14. The testing is performed with a combination/hybrid pulse generator with an effective output impedance of 2 Ω . The setup for the overvoltage stress is shown in Figure 15 with all testing performed with power applied to the SN65LBC184 circuit.

High voltage transient testing is done on a sampling basis. VI(peak) 0.5 Vp 1.2 μ s 50 μ s 50

NOTE

Figure 14. Short-Circuit Current Waveforms

The SN65LBC184 is tested and evaluated for both maximum (single pulse) as well as life test (multiple pulse)capabilities. The SN65LBC184 is evaluated against transients of both positive and negative polarity and all testing is performed with the worst-case transient polarity. Transient pulses are applied to the bus pins (A & B) across ground as shown in Figure 15.

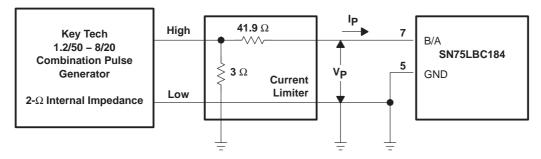
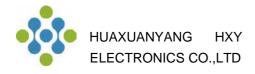


Figure 15. Overvoltage-Stress Test Circuit

An example waveform as seen by the SN65LBC184 is shown in Figure 16. The bottom trace is current, the middle trace shows the clamping voltage of the device and the top trace is power as calculated from the voltage and current waveforms. This example shows a peak clamping voltage of 16 V, peak current of 33.6 A yielding an absorbed peak power of 538 W.

NOTE

A circuit reset may be required to ensure normal data communications following a transient noise pulse of greater than 250 W peak.



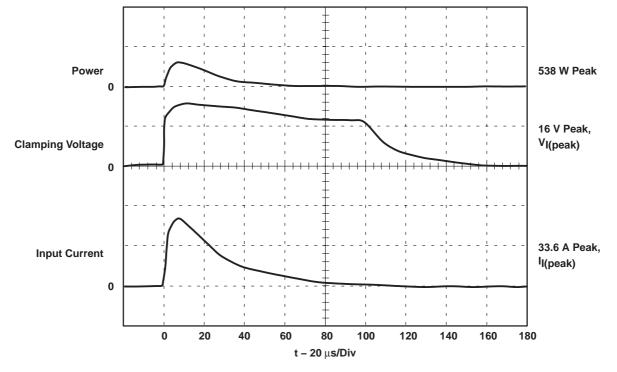


Figure 16. Typical Surge Waveform Measured At Terminals 5 and 7

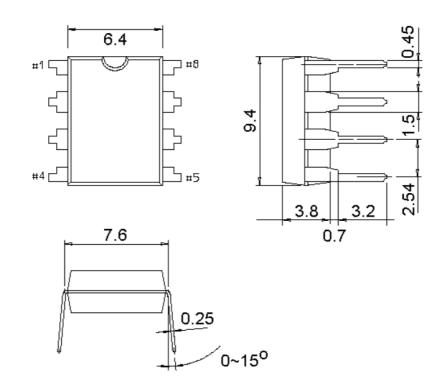
ORDERING INFORMATION

Package	Oder No.	Compliance	Operating temperature	Supplied As
SOP-8	SN65LBC184DR	RoHS, Green	-40°C to +85°C	Tube
DIP-8	SN65LBC184N	RoHS, Green	-40°C to +85°C	Tube
SOP-8	SN75LBC184DR	RoHS, Green	-0°C to +70°C	Tube
DIP-8	SN75LBC184N	RoHS, Green	-0°C to +70°C	Tube

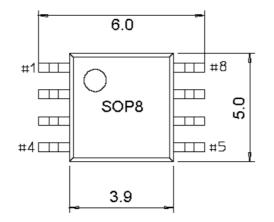


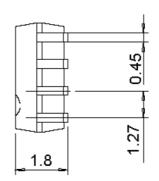
PACKAGE OUTLINE DIMENSIONS

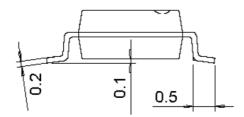
DIP-8



SOP-8









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